

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

SB80W06T — Schottky Barrier Diode (Twin Type • Cathode Common) 60V, 8A Rectifier

Applications

· High frequency rectification (switching regulators, converters, choppers).

Features

- Low forward voltage (VF max=0.6V).
- · Fast reverse recovery time.
- · Low switching noise.
- · High reliability due to highly reliable planar structure.
- · Halogen free compliance.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	V _{RRM}		60	V
Nonrepetitive Peak Reverse Surge Voltage	V _{RSM}		66	V
Average Output Current	I _O *2	50Hz resistive load, sine wave Tc=130°C	4	Α
	I _O *1	50Hz resistive load, sine wave Tc=83°C	8	А
Surge Forward Current	I _{FSM}	50Hz sine wave, 1 cycle	40	А
Junction Temperature	Tj		-55 to +150	°C
Storage Temperature	Tstg		-55 to +150	°C

Note) *1. Indicates the total value

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^{*2.} Value per element

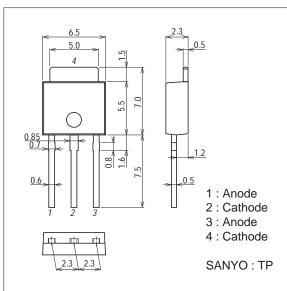
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
	Syllibol		min	typ	max	O I III
Reverse Voltage	VR	I _R =1mA, Tj=25°C *2	60			V
Forward Voltage	VF	I _F =3.0A, Tj=25°C *2			0.6	V
Reverse Current	IR	V _R =30V, Tj=25°C *2			0.1	mA
Interterminal Capacitance	С	V _R =10V, Tj=25°C *2		130		pF
Transient Thermal Resistance	Rth(j-c)	Junction-Case : Smoothed DC		6		°C/W

Note) *2. Value per element

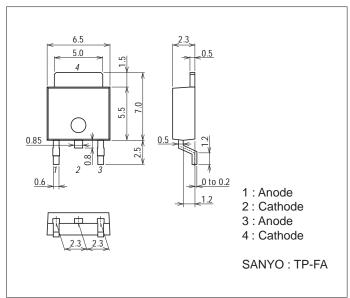
Package Dimensions

unit : mm (typ) 7518-001

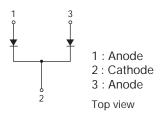


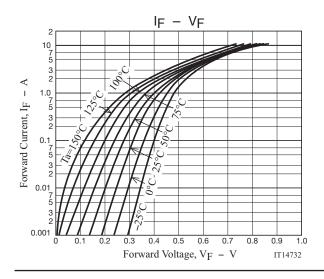
Package Dimensions

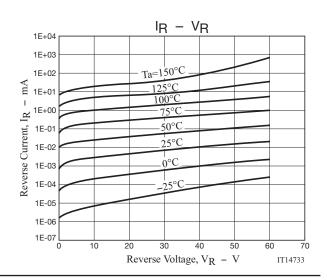
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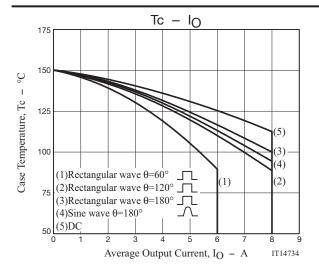


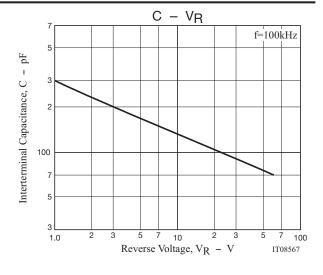
Electrical Connection











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